

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	44	(wolfram near2 kluge).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:11
2	BRS	L2	14	(dietmar near2 eggert).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:12
3	BRS	L3	7	(1 2) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:38
4	BRS	L4	0	3 and (esd (electrostatic near3 discharge))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:31
5	BRS	L5	41	(1 2) not 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:31
6	BRS	L6	1	5 and (esd (electrostatic near3 discharge))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:31
7	BRS	L7	447	(inductor inductance) with (turn coil) with (ESD capacitance zener (voltage near2 limiting)) with parasitic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:38
8	BRS	L8	230	(inductor inductance) with (layer) with (ESD capacitance zener (voltage near2 limiting)) with parasitic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:38
9	BRS	L9	33	L7 and L8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:38
10	BRS	L10	2	9 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:42
11	BRS	L11	6	(inductor inductance) with (turn coil) with (ESD zener (voltage near2 limiting)) with parasitic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:39
12	BRS	L12	38	(inductor inductance) same (turn coil) same (ESD zener (voltage near2 limiting)) same parasitic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:40

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13	BRS	L13	2	(11 12) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:40
14	BRS	L14	4	(inductor inductance) same (turn coil) same (electrostatic near5 (protect protection protected protecting)) same parasitic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:40
15	BRS	L15	16	(esd (electrostatic with (protect\$3 discharg\$3))) with (lump distributed) with (parasitic parasite)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:41
16	BRS	L16	5	(14 15) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:44
17	BRS	L17	3	(esd (electrostatic with (protect\$3 discharg\$3))) same lump same distributed	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:43
18	BRS	L18	18	(esd electrostatic) same lump same distributed	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:43
19	BRS	L19	14	(lump with distributed) with capacitance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:43
20	BRS	L20	2	(lump with (esd electrostatic) with capacitance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:44
21	BRS	L21	0	(17 18 19 20) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:45
22	BRS	L22	130	(distributed with (esd electrostatic) with capacitance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:45
23	BRS	L23	7	22 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:47
24	BRS	L24	0	(eos) with (lump distributed) with (parasitic parasite)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:46

	Type	L #	Hits	Search Text	DBs	Time Stamp
25	BRS	L25	0	(lump with (eos) with capacitance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:46
26	BRS	L26	3	(distributed with (eos) with capacitance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:47
27	BRS	L27	7	(eos) same lump same distributed	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:47
28	BRS	L28	0	(26 27) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:49
29	BRS	L29	552	(lumped distributed) With (esd eos (electrostatic near3 (discharg\$3 protect\$3)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:48
30	BRS	L30	42	29 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:54
31	IS&R	L31	3805	(361/54,56,111).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:51
32	IS&R	L32	2098	(336/200).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:51
33	BRS	L34	0	31 and 32	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:52
34	IS&R	L35	3805	(361/54,56,111).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:52
35	BRS	L36	131	L35 and (low near2 pass near2 filter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:52
36	BRS	L37	404	L35 and ((coil near2 (turn revolution)) loop)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:52

	Type	L #	Hits	Search Text	Dbs	Time Stamp
37	BRS	L38	56	L35 and (((coil near2 (turn revolution)) loop) with (esd eos mosfet zener))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:54
38	BRS	L39	15	(36 37 38) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:58
39	BRS	L40	2	(inductor with coil with (turn portion)) with (esd eos (electrostatic near3 protect\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:56
40	BRS	L41	3235	(series cascaded) with (esd eos (electrostatic near3 protect\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:56
41	BRS	L42	4	(inductance with coil with (turn portion)) with (esd eos (electrostatic near3 protect\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:57
42	BRS	L43	52	(series cascaded) with (esd eos (electrostatic near3 protect\$3)) with inductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:57
43	BRS	L44	130	(multiple near3 (inductor inductance)) with (single near3 (inductor inductance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:57
44	BRS	L45	2	(inductance with coil with (section tap)) with (esd eos (electrostatic near3 protect\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 15:58
45	BRS	L46	12	(42 43 44 45) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:01
46	BRS	L47	370	(31 32) and 41	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:04
47	BRS	L48	31	(47) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:16
48	BRS	L49	383	(single with turn with inductor)	USPAT	2006/08/18 16:03
49	BRS	L50	247	(single near5 turn near5 inductor)	USPAT	2006/08/18 16:03

	Type	L #	Hits	Search Text	DBs	Time Stamp
50	BRS	L51	759	(single with turn with inductor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:03
51	BRS	L52	480	(single near5 turn near5 inductor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:03
52	BRS	L53	34	(single near5 turn near5 inductor) with (multiple near5 turn near5 inductor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:04
53	BRS	L54	53	(31 32) and (51 52)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:04
54	BRS	L55	4	53 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:05
55	BRS	L56	2	54 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:19
56	BRS	L57	51	54 not 56	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:15
57	BRS	L58	451	(parasitic with capacitance) and (31 32)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:16
58	BRS	L59	230	58 and (esd electrostatic)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:16
59	BRS	L60	16	59 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:18
60	BRS	L61	84	inductor same diodes same capacitance same (esd electrostatic)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:19
61	BRS	L62	7	61 and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:20

62	IS&R	L63	2	((("5969929") or ("5576680"))).PN.	USPAT	2006/08/18 16:20
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	Type	L #	Hits	Search Text	DBs	Time Stamp
63	BRS	L64	21	("5969929").URPN.	USPAT	2006/08/18 16:20
64	BRS	L65	30	("5576680").URPN.	USPAT	2006/08/18 16:21
65	BRS	L66	2	(64 65) and @pd>"20060303"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/08/18 16:21